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FORM PTO-1449 <b>FIRST SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT</b>				ATTY. DOCKET NO. <b>2132.0180000</b>			
				APPLICATION NO. <b>10/796,413</b>			
				FIRST NAMED INVENTOR <b>Xiangfeng Duan</b>			
				FILING DATE <b>March 10, 2004</b>			
				ART UNIT <b>2818</b>			
<b>U.S. PATENT DOCUMENTS</b>							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE
	AA1						
	AB1						
	AC1						
	AD1						
	AE1						
	AF1						
	AG1						
<i>MS</i>	AH1	6,586,785	07/2003	Flagan <i>et al.</i>			
<i>MM</i>	AI1	6,723,606	04/2004	Flagan <i>et al.</i>			
	AJ1						
	AK1						
<b>FOREIGN PATENT DOCUMENTS</b>							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION
	AL1						Yes No
	AM1						Yes No
	AN1						Yes No
	AO1						Yes No
	AP1						Yes No
<b>OTHER (Including Author, Title, Date, Pertinent Pages, etc.)</b>							
	AR	1					
<i>MA</i>	AS	1	McCarthy, W., O'REILLY NETWORK™ <i>Quantum Dots and Programmable Matter</i> (visited January 12, 2004) <a href="http://www.oreillynet.com/pub/a/network/2004/01/09/quantumdots.html">http://www.oreillynet.com/pub/a/network/2004/01/09/quantumdots.html</a> , 5 pages, Copyright 2000-2004 O'Reilly & Associates, Inc.				
<i>MS</i>	AT	1	Mandal, S., "QUANTUM DOTS," E & ECE, IIT Kharagpur, Roll: 9819107, 24 pages, August 29, 2001.				
EXAMINER <i>MS</i>					DATE CONSIDERED <i>3/30/04</i>		
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							

FORM PTO-1449

## INFORMATION DISCLOSURE STATEMENT

ATTY. DOCKET NO.

2132.0180000

APPLICATION NO.

To be assigned

FIRST NAMED INVENTOR

Duan et al.

FILING DATE

March 10, 2004

ART UNIT

To be assigned

## U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE
<i>MM</i>	AA1	5,043,940	08/27/1991	Harari			07/17/1989
<i>MM</i>	AB1	5,434,825	07/18/1995	Harari			09/03/1993
<i>MM</i>	AC1	6,222,762 B1	04/24/2001	Guterman et al.			08/07/1997
<i>MM</i>	AD1	6,275,419 B1	08/14/2001	Guterman et al.			10/13/2000
<i>MM</i>	AE1	6,317,363 B1	11/13/2001	Guterman et al.			10/13/2000
<i>MM</i>	AF1	6,317,364 B1	11/13/2001	Guterman et al.			10/13/2000
<i>MM</i>	AG1	6,577,532 B1	06/10/2003	Chevallier			08/31/2000
	AH1						
	AI1						
	AJ1						
	AK1						

## FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION
	AL1						Yes No
	AM1						Yes No
	AN1						Yes No
	AO1						Yes No
	AP1						Yes No

## OTHER (Including Author, Title, Date, Pertinent Pages, etc.)

<i>MM</i>	AR	1	Silicon Storage Technology, Inc., "Technical Comparison of Floating Gate Reprogrammable Nonvolatile Memories", <i>Technical Paper</i> , November 2001, copyright 2002, 8 pages.				
	AS	1					
	AT	1					

EXAMINER

*MM*

DATE CONSIDERED

9/30/06

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